

L Number	Hits	Search Text	DB	Time stamp
1	3327	varactor and diode	USPAT; US-PGPUB	2003/12/24 14:51
2	547	(varactor and diode) and well and isolation	USPAT; US-PGPUB	2003/12/24 14:51
3	327	((varactor and diode) and well and isolation) and (gate or electrode)	USPAT; US-PGPUB	2003/12/24 14:51
4	296	((varactor and diode) and well and isolation) and (gate or electrode)) and (diffusion or diffused or impurity or implanted or doped or doping or source or drain)	USPAT; US-PGPUB	2003/12/24 14:52
5	277	((varactor and diode) and well and isolation) and (gate or electrode)) and (diffusion or diffused or impurity or implanted or doped or doping or source or drain)) and @ad<20020814	USPAT; US-PGPUB	2003/12/24 14:37
6	2357	varactor and diode	EPO; JPO; DERWENT; IBM_TDB	2003/12/24 14:51
7	1	(varactor and diode) and well and isolation	EPO; JPO; DERWENT; IBM_TDB	2003/12/24 14:51
8	263	(varactor and diode) and (gate or electrode)	EPO; JPO; DERWENT; IBM_TDB	2003/12/24 14:51
9	104	((varactor and diode) and (gate or electrode)) and (diffusion or diffused or impurity or implanted or doped or doping or source or drain)	EPO; JPO; DERWENT; IBM_TDB	2003/12/24 14:52